Product data sheet

1. General description

Ultrafast power diode in a SMC package.

2. Features and benefits

- Fast switching
- SMC package
- High voltage capability
- · Low forward voltage drop
- Low leakage current
- · Low thermal resistance
- Soft recovery characteristic

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- · use in switching power supplies, inverters and as free wheeling diodes
- · High frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit				
Absolute	Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage		600	V				
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le 95$ °C; Fig. 1; Fig. 2; Fig. 3	8	Α				
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{lead} \le$ 95 °C; square-wave pulse	16	А				
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	А				
		t_p = 8.3 ms; $T_{J(init)}$ = 25 °C; sine-wave pulse	200	Α				

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v 14 A
2	A	anode	1 2	K

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
MUR860	SMC	MUR860J	Reel	3000	SMCS	16-Aug-2017
		MUR860,118				

7. Marking

Table 4. Marking codes

Type number	Marking codes	Marking codes			
	Assembly factory	y: S Assembly factory: E			
MUR860	860J	JS 860JE			

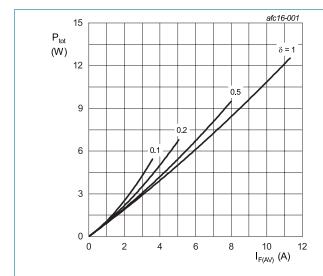
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8. Limiting values

Table 5. Limiting values

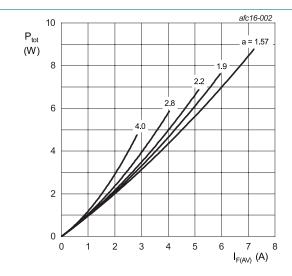
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le 95$ °C; Fig. 1; Fig. 2; Fig. 3	8	Α
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{lead} ≤ 95 °C; square-wave pulse	16	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	200	Α
T _{stg}	storage temperature		-65 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.918 \text{ V; } R_s = 0.0168 \text{ } \Omega \end{split}$$

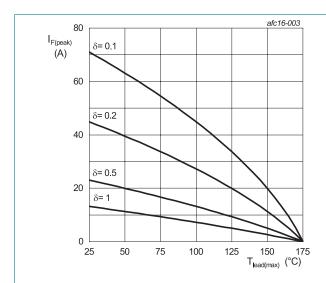
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

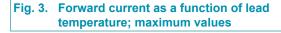


a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.918 V; R_s = 0.0168 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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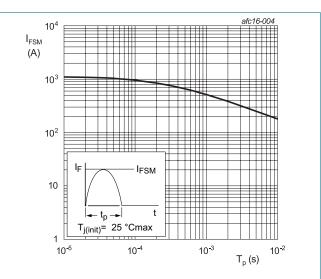


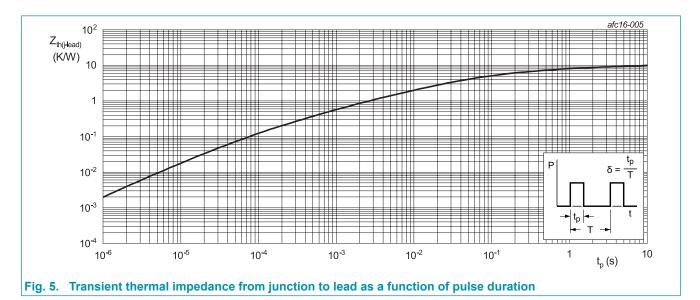
Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

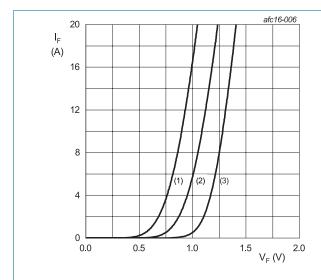
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	Fig. 5		-	-	10	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	75	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics					•	'
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	-	1.25	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	-	1.05	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C		-	-	10	μA
		V _R = 600 V; T _j = 150 °C		-	-	400	μΑ
Dynamic	characteristics						
Q _r	reverse charge	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$		-	494	-	nC
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 125 \text{ °C}; Fig. 7$		-	983	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/us};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$		-	66	90	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$		-	93	-	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 125 \text{ °C}; Fig. 7$		-	130	-	ns
I _{RM}	peak reverse recovery current	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$		-	11	-	А
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_i = 125 \text{ °C}; Fig. 7$		-	15	-	А



 V_o = 0.918 V; R_s = 0.0168 Ω

(1) $T_j = 150 \,^{\circ}\text{C}$; typical values (2) $T_j = 150 \,^{\circ}\text{C}$; maximum values (3) $T_j = 25 \,^{\circ}\text{C}$; maximum values

Fig. 6. Forward current as a function of forward voltage

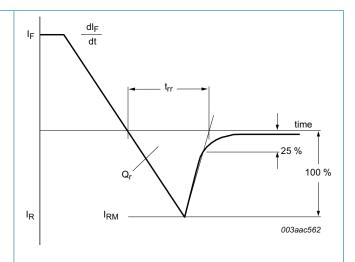
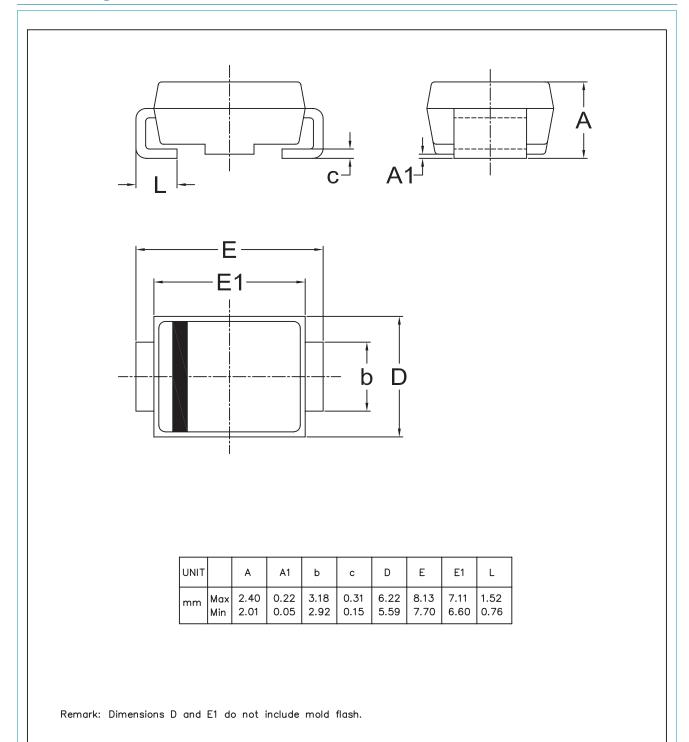


Fig. 7. Reverse recovery definitions; ramp recovery

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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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